Optical study of RbV₃Sb₅: Multiple density-wave gaps and phonon anomalies

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Temperature-dependent reflectivity studies on the nonmagnetic kagome metal RbV₃Sb₅ in a broad energy range (50–20000 cm⁻¹, equivalent to 6 meV–2.5 eV) down to 10 K are reported. Below $T_{CDW} = 102$ K, the optical spectra demonstrate a prominent spectral-weight transfer from low to higher energies as the fingerprint of the charge-density-wave (CDW) formation with the opening of a partial gap. A detailed analysis reveals two energy scales of respectively ~800 cm⁻¹ (100 meV) and 360 cm⁻¹ (45 meV), the latter visible below 50 K only. Additionally, two modes at respectively 160 cm⁻¹ (20 meV) and 430 cm⁻¹ (53 meV) can be traced both above and below T_{CDW} . They show strong anomalies already above T_{CDW} with a further renormalization across the transition, suggesting the importance of the electron-phonon coupling in RbV₃Sb₅ in both normal and CDW states. While the 160 cm⁻¹ mode can be attributed to the E_{1u} phonon, the 430 cm⁻¹ mode could not be reproduced in our phonon calculations. The antiresonance nature of this mode suggests a nontrivial electron-phonon coupling in RbV₃Sb₅. A distinct localization peak observed at all temperatures signals damped electron dynamics, whereas the reduced Drude spectral weight manifests moderate deviations from the band picture in RbV₃Sb₅.

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I. INTRODUCTION

Kagome metals became model compounds for studying the effects of correlations along with topologically nontrivial electronic states [1]. Driven by the spatially separated metallic kagome planes, electronic structures of kagome metals feature flat bands and linearly dispersing topological Dirac bands, as has been shown in several magnetic systems of recent interest [2–5].

The nonmagnetic AV_3Sb_5 (A = K, Rb, Cs) series opens up new opportunities to study the electronic properties of the kagome metals [6]. These compounds crystallize in the P6/mmm space group with V atoms forming a kagome lattice and Sb1 atoms filling the centers of the hexagons. The kagome networks are stacked along the *c* axis and separated by Sb2 honeycomb layers and *A* alkali atoms. This results in an overall quasi-two-dimensional (2D) structure with well-isolated kagome planes. All key features of a nearest-neighbor kagome metal—linear bands, saddle points, and flat bands—can be indeed distinguished in the electronic structures of AV_3Sb_5 [7].

Transport and magnetic measurements on AV_3Sb_5 revealed a strong anomaly at $T_{CDW} = 102$ K for RbV₃Sb₅ [8] (78 K for KV₃Sb₅ [6] and 94 K for CsV₃Sb₅ [9]). Moreover, RbV₃Sb₅ becomes superconducting at $T_c = 0.92$ K [8] (0.93 K for KV₃Sb₅ [10] and 2.5 K for CsV₃Sb₅ [9]). While the exact nature of the high-temperature anomaly is still under debate, the robust nature of this transition under external magnetic fields suggests a charge-density wave (CDW) as the plausible origin. Indeed, band saddle points (van Hove singularities) observed in AV_3Sb_5 in the vicinity of the Fermi level [11–13] should lead to a CDW instability of a kagome metal [14–16]. The resulting CDW state is quite unusual, as it features a large anomalous Hall effect [17,18], multiple energy gaps [11,19,20], and intrinsic chirality [18,21,22]. One general and hitherto unresolved issue is the clear distinction between the bulk and surface effects in the CDW state of AV₃Sb₅. For example, two different coexisting superstructures were observed in surface-sensitive measurements of CsV₃Sb₅ [23], but only one of them is believed to occur in the bulk [24,25]. A temperature-driven rearrangement of the CDW order has been proposed in CsV₃Sb₅ as well [26].

Despite many similarities shared by all three compounds— KV_3Sb_5 , RbV_3Sb_5 , and CsV_3Sb_5 —they feature somewhat different energy scales and, possibly, different underlying interactions. Density-functional-theory (DFT) band-structure calculations could perfectly reproduce the optical response of CsV_3Sb_5 [27], but not of KV_3Sb_5 [28], suggesting that deviations from the band picture may be enhanced across the series as the size of the alkaline metal is reduced. This motivates a comparative optical study of RbV_3Sb_5 as the possible intermediate case (see Fig. 1).

Below, we show that this compound is indeed intermediate in terms of its bands near the Fermi level and their saddle points. We further confirm that several pertinent features hindered electron dynamics witnessed by the low-energy

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FIG. 1. Crystal structure of RbV₃Sb₅. The V network is stabilized with the Sb1 atoms. The V-Sb1 kagome net is separated by the Sb2 honeycomb sheets and Rb atoms. Two possible structural distortions below T_{CDW} are the star-of-David and trihexagonal structures [27,28].

localization peak, and strong electron-phonon coupling revealed by the broadening of the phonon modes—are common across the AV_3Sb_5 series. Additionally, we are able to detect two distinct CDW gaps in RbV₃Sb₅. These gaps are integral to the putative topological state but could be previously observed with surface-sensitive techniques only [12,29]. Our optical

study confirms their bulk nature, thus setting a benchmark for the CDW state of AV_3Sb_5 .

II. METHODS

A. Experiment

High-quality single crystals were prepared as explained in Refs. [6,10]. For the optical measurements, a sample with the dimensions of $\sim 1.5 \times 1.5 \text{ mm}^2$ surface area was used, while the thickness of the specimen was around 0.2 mm. The sample was freshly cleaved prior to the optical experiments. On the same crystal, four-point resistivity measurements were performed in order to determine the CDW transition temperature and confirm the stoichiometry. The kink at 102 K marking the CDW transition [Fig. 2(b), inset], as well as the overall behavior agrees well with the previous reports [8].

Temperature-dependent reflectivity measurements in the *ab* plane over a broad frequency range from 50 to 20 000 cm⁻¹ (6 meV–2.5 eV) were performed down to 10 K. While for the high-energy range ($\omega > 600 \text{ cm}^{-1}$) a Bruker Vertex 80v spectrometer with an incorporated Hyperion IR microscope was used, the low-energy range was measured with a Bruker IFS113v spectrometer and a custom-built cryostat. Freshly evaporated gold mirrors served as a reference in these measurements. The absolute value of the reflectivity was obtained by an *in situ* gold-overcoating technique in the far-infrared range, as described in Ref. [30].

Below 50 cm⁻¹, we use the standard Hagen-Rubens extrapolation, considering the metallic nature of our sample, while for the high-energy range we utilize x-ray scattering functions for extrapolating the data [31]. The optical



FIG. 2. (a) Temperature-dependent reflectivity over a broad frequency range measured in the *ab* plane. (b) Calculated real part of the optical conductivity. The inset shows the resistivity values obtained from the Hagen-Rubens fit of the reflectivity overlapped with the dc resistivity measurement. At 102 K, a kink in the resistivity marks the CDW transition that is better visible in the first derivative. (c) Temperature dependence of the dielectric loss function. The position of the maximum indicates the screened plasma frequency, with temperature dependence given in the inset. A clear increase is observed across the CDW transition at $T_{CDW} = 102$ K. This change can also be seen in the frequency-dependent dielectric permittivity at room temperature and at 10 K shown in another inset of the same panel. The high-energy limit is taken as ε_{∞} .

conductivity is then calculated from the measured reflectivity via Kramers-Kronig analysis.

B. Computation

Density-functional-theory (DFT) calculations of the band structure and optical conductivity were performed in the WIEN2K [32,33] code using the Perdew-Burke-Ernzerhof flavor of the exchange-correlation potential [34]. We used experimental structural parameters from Ref. [6] for the undistorted RbV₃Sb₅ structure, whereas possible CDW structures were obtained by a structural relaxation in VASP [35,36] similar to Refs. [27,28]. Spin-orbit coupling was included for the calculations of band structure and optical conductivity.

Self-consistent calculations and structural relaxations were converged on the $24 \times 24 \times 12$ k mesh for the undistorted RbV₃Sb₅ structure (normal state) and $12 \times 12 \times 12$ k mesh for the distorted structures (CDW). Optical conductivity was calculated on the k mesh with up to $100 \times 100 \times 50$ points for the normal state and $36 \times 36 \times 36$ points for the CDW states.

III. RESULTS AND DISCUSSION

A. Optical spectra

Figure 2(a) displays the temperature-dependent reflectivity of RbV₃Sb₅. The high reflectivity values at low frequencies, as well as the Drude-like increase in the optical conductivity [Fig. 2 (b)], demonstrate the metallic nature of the sample. Conductivity values in the $\omega \rightarrow 0$ limit are obtained from the Hagen-Rubens fit of the reflectivity [Fig. 3(a)] and match well with the four-probe dc resistivity measurements performed on the same sample, as shown in the inset of Fig. 2(b). Upon going through the CDW transition, significant changes in the optical properties occur. Around 0.15 eV, a dip develops in the reflectivity, echoed by a spectral-weight transfer to an additional peak at around 0.17 eV in the optical conductivity below $T_{\rm CDW}$. The low-energy optical conductivity is highlighted in Fig. 3(b), where the spectral-weight transfer to higher frequencies is shown by the green arrow. The solid circles in the figure represent the dc conductivity values, whereas the orange arrow highlights the Fano resonance. This Fano resonance is one of the signatures of the strong electron-phonon coupling that will be further discussed in Sec. III E.

The CDW transition also affects the free-carrier dynamics, as seen from the evolution of the screened plasma frequency $\omega_p^{\text{screened}}$ which can best be estimated from the position of the maximum in the dielectric loss function $-\text{Im}\{1/\tilde{\varepsilon}\}$ [37]. The real plasma frequency is masked by the interband transitions, but it can be calculated as $\omega_p = \omega_p^{\text{screened}} \sqrt{\varepsilon_{\infty}}$ where we use the temperature-independent $\varepsilon_{\infty} = 6$ estimated from the high-energy limit of the permittivity, as shown in the inserted from the abrupt increase around T_{CDW} is expected in the real plasma frequency, too.

As the plasma frequency can also be given as $\omega_p^2 \propto n/m^*$ (*n* is the carrier density and m^* is the effective mass), the overall increase in ω_p can be attributed to either increasing carrier density or decreasing effective mass. Both scenarios are possible in RbV₃Sb₅. The CDW transition in RbV₃Sb₅ gaps out some of the electronic bands [12,29], thus affecting



FIG. 3. (a) Low-energy reflectivity and the corresponding Hagen-Rubens fits at selected temperatures. (b) Low-energy optical conductivity shown for the same selected temperatures. The solid lines are the fits to the experimental spectra as described in the text. While at 10 K the localization peak lies outside of the measurement range, its position can be estimated assuming linear temperature dependence and using the high-energy tail, which is still visible in our data. The solid circles are the fixed dc conductivity values obtained from the Hagen-Rubens fits. The orange arrow marks the Fano resonance, and the green arrow illustrates the spectral-weight transfer to an additional peak that appears below T_{CDW} .

 m^* . Concurrently, Hall effect measurements on KV₃Sb₅ [17] and CsV₃Sb₅ [18] suggest that below T_{CDW} the carrier density increases.

B. Decomposition

Different contributions to the optical spectra are modeled with the Drude-Lorentz approach,

$$\tilde{\varepsilon}(\omega) = \varepsilon_{\infty} - \frac{\omega_{p,\text{Drude}}^2}{\omega^2 + i\omega/\tau_{\text{Drude}}} + \sum_{j} \frac{\Omega_j^2}{\omega_{0,j}^2 - \omega^2 - i\omega\gamma_j}.$$
 (1)

Here, $\omega_{p,\text{Drude}}$ and $1/\tau_{\text{Drude}}$ are the plasma frequency and the scattering rate of the itinerant carriers, respectively. The parameters $\omega_{0,j}$, Ω_j , and γ_j describe the resonance frequency, width, and the strength of the *j*th excitation, respectively. Finally, ε_{∞} stands for the high-energy contributions to the real part of the dielectric permittivity ($\tilde{\varepsilon} = \varepsilon_1 + i\varepsilon_2$).

In addition to the classical Lorentzian and Drude contributions, a Fano-like shaped peak is observed around 400 cm^{-1}



FIG. 4. Decomposition of the optical conductivity at (a) room temperature, (b) 110 K > T_{CDW} , and (c) 10 K < T_{CDW} consisting of a Drude peak (purple), a localization peak (green), a phonon (yellow), a Fano resonance (blue), and multiple interband transitions (orange). Note that at 10 K only the tail of the localization peak is visible, but it is sufficient to estimate the peak position.

along with the strongly temperature-dependent absorption feature that appears around 500 cm⁻¹ at room temperature and systematically shifts to lower energies upon cooling. In line with the previous optical studies of the kagome metals, this latter feature is assigned to a so-called localization peak [27,28,38] that signals hindered electron dynamics. The nature and temperature evolution of this peak are further discussed in Sec. III C below.

Total dielectric permittivity takes the form

$$\tilde{\varepsilon}(\omega) = \tilde{\varepsilon}_{\text{Drude}}(\omega) + \tilde{\varepsilon}_{\text{Lorentz}}(\omega) + \tilde{\varepsilon}_{\text{local}}(\omega) + \tilde{\varepsilon}_{\text{Fano}}(\omega).$$
 (2)

The complex optical conductivity ($\tilde{\sigma} = \sigma_1 + i\sigma_2$) is then calculated as

$$\tilde{\sigma}(\omega) = -i\omega[\tilde{\varepsilon}(\omega) - \varepsilon_{\infty}]/4\pi.$$
(3)

Examples of the decomposed spectra are given in Fig. 4. The narrowing of the Drude contribution along with the redshift of the localization peak are clearly visible in the spectra. Furthermore, the overall sharpening of the interband transitions down to 110 K and the redistribution of the spectral weight at T_{CDW} are demonstrated.



FIG. 5. (a) Temperature dependence of the localization peak obtained after subtracting all other contributions from the experimental spectra. The inset shows the temperature evolution of the peak position. The error bars at 10 and 25 K arise from the fact that the peak center lies outside of the frequency range of our measurement. (b) Elastic scattering (τ) and backscattering (τ_b) of the localization peak of RbV₃Sb₅. (c) Scattering rate of the Drude component overlaid with the dc resistivity.

C. Localization peak

Having described the general decomposition of the optical spectrum, we now turn to a more detailed analysis of the localization peak. Its temperature evolution is plotted in Fig. 5(a), after subtracting the Drude, phonon, and interband contributions from the experimental data. The strong and linear redshift of the peak position upon cooling, given in the inset of Fig. 5(a), makes this feature clearly distinguishable from the interband transitions. Furthermore, the interband transitions are well reproduced by DFT calculations, as discussed in Sec. III F. The absence of this peak in the calculated spectrum gives further evidence for its interpretation in terms of an intraband process.

Localization, or displaced Drude peaks in the optical conductivity can have different natures and have been reported for transition-metal oxides [39], cuprate superconductors [40], and organic conductors [41]. It has been shown that the partial localization of the charge carriers shifts the Drude peak to finite frequencies. Different mechanisms of this localization can be envisaged, including electron-phonon interactions, electronic correlations, as well as localization of carriers caused by a structural disorder in the material.

Among the different theoretical frameworks that have been developed for the localization peak [42,43], we choose the model of a displaced Drude peak by Fratini *et al.* [44], where

the classical Drude response is modified with the backscattering of the electrons, leading to a shift of the zero-frequency response to a finite value:

$$\tilde{\sigma}_{\text{local}}(\omega) = \frac{C}{\tau_{\text{b}} - \tau} \frac{\tanh\left\{\frac{\hbar\omega}{2k_{\text{B}}T}\right\}}{\hbar\omega} \times \text{Re}\left\{\frac{1}{1 - i\omega\tau} - \frac{1}{1 - i\omega\tau_{\text{b}}}\right\}.$$
 (4)

Here, *C* is a constant, \hbar is the reduced Planck constant, and $k_{\rm B}$ the Boltzmann constant. Furthermore, τ stands for the elastic scattering time of the standard Drude model, whereas τ_b is the backscattering of the electrons due to localization effects. Here, one should also point out that $\tau_b > \tau$ with a longer timescale. The formalism, as presented in Ref. [44], applies to localization effects that are caused by interactions of charge carriers with low-energy degrees of freedom, such as phonons, electric or magnetic fluctuations, which lead to a backscattering of the electrons.

For a further insight, we plotted the elastic scattering and the backscattering of the localization peak in Fig. 5(b). As noted by the arrow, the elastic scattering shows a slight change across the CDW transition. This change corresponds to a partial gapping of the Fermi surface [12,29] and the change in the carrier density across T_{CDW} . On the other hand, the backscattering mechanism seems to be unaffected by the CDW formation. In Fig. 5(c), we have also shown the elastic scattering of the Drude component, which is overlaid with the dc resistivity. The remarkably similar temperature evolution suggests that the dc transport is mainly governed by the Drude component and not by the incoherent localization peak.

Regardless of the exact microscopic interpretation of this localization peak, a striking feature of its temperature evolution is the insensitivity to T_{CDW} . The effects that hinder electron dynamics seem to be purely thermal in nature and vanish in the $T \rightarrow 0$ limit. A similar behavior is observed in CsV₃Sb₅ [27], but not in KV₃Sb₅ where the localization peak also shifts toward low energies upon cooling, yet it saturates at around 300 cm⁻¹ and does not reach zero energy even at 10 K [28].

D. Energy scale of the charge-density wave

One of the key features of the AV₃Sb₅ family is the formation of a density-wave state accompanied by a superstructure [9]. While there is a consensus on the 2×2 in-plane modulation [22,45–49], both twofold and fourfold modulations along the c axis have been proposed [23,48,50,51]. This superstructure formation is concomitant with the reduction in the density of states at the Fermi level. Recent quantum oscillation [50] and angle-resolved photoemission spectroscopy (ARPES) [11,12] studies suggested that vanadium bands around the M point become gapped, in line with theoretical proposals of band saddle points at M as the main origin of the density-wave instability [15,52]. The presence of multiple d bands in AV₃Sb₅ [7] implies that this instability can have more than one energy scale revealed by several gap features that were indeed detected spectroscopically, but only with surface-sensitive techniques, so far [11,12,20].



FIG. 6. (a) Temperature-dependent interband transitions. The curves are shifted by $2000 \ \Omega^{-1} \text{ cm}^{-1}$ for clarity. The gradual sharpening of the interband transitions on cooling is interrupted with the CDW formation that manifests itself by the shift of the spectral weight toward higher energies (pink arrow). Below 50 K, an additional absorption appears around 50 meV and can be most clearly seen in the nonshifted spectra of (c). (b) Interband transitions of RbV₃Sb₅ as a function of temperature below T_{CDW} down to 50 K. The 110 K data are shown as reference for the change across T_{CDW} . (c) Interband transitions as a function of temperature below 50 K show the emergence of the second energy scale at low temperatures. The arrows in (a) and (b) demonstrate the SW transfer across T_{CDW} and below 50 K.

Here, we show that these multiple gaps can be corroborated by the bulk optical probe. Figure 6(a) displays temperature dependence of the interband transitions and demonstrates the sharpening of the absorption on cooling down to T_{CDW} . Below T_{CDW} , the spectral weight shifts to higher energies (pink arrow), indicating the opening of a CDW gap. A very different behavior is seen at even lower temperatures, below 50 K, where the low-energy spectral weight around 50 meV starts growing again [Fig. 6(b)] because of the redistribution from even lower energies (cyan arrow). A convenient way to trace these spectral-weight transfers is by using the spectral-weight ratio below and above T_{CDW} , similar to, e.g., iron pnictides [53].

The spectral weight (SW) is obtained as $\frac{120}{\pi} \int_0^{\omega} \sigma_1(\omega) d\omega$. The cutoff value of ω is chosen through the entire measured range taking into account only the interband transitions, as shown in Fig. 6. The SW ratio, namely, SW(*T*)/SW(110 K), gives the characteristics of the SW transfers (transfer



FIG. 7. (a), (b) Frequency dependence of SW(T)/SW(110 K) as a function of temperature. The opening of the primary gap is seen in (a), where the arrow further shows the emergence of a secondary effect at 50 K causing an increase in SW around 50 meV. The further depletion of the SW due to the emergence of a second energy scale at low energies is demonstrated with an arrow in (b). (c) Second derivative of the spectral-weight ratio (curves are shifted for clarity), with the black lines showing the zero line taken from the 90 K spectrum. The zero-crossing positions marked by circles give a rough estimate for the energy scale of the CDW gaps. (d) Temperature dependence of both CDW gap energies. At 50 K, the second (smaller) gap is shown with an open circle, as the effect is tiny compared to the 25 and 10 K data. However, around 50 meV there is clearly an additional SW contribution at 50 K compared to 75 and 90 K.

direction, energy scales, etc.) in the CDW state [54]. If there is a SW transfer from high to low energies (e.g., a narrowing of the Drude peak), the ratio is above "1" at low energies and then approaches unity. On the other hand, when there is a SW transfer from low to high energies, the ratio is below "1" until the energy transfer is completed. Here, we analyze only the spectral weight related to the interband transitions and thus directly probe the energy scales associated with the CDW.

In Figs. 7(a) and 7(b), the SW ratio for several temperatures below T_{CDW} is plotted. The SW transfer happens in the energy

range below 0.35 eV, as the ratio levels off to unity at higher energies. The SW ratios at 75 and 90 K are qualitatively similar, while at 50 K the overall curvature increases, with an additional SW transfer observed at 10 and 25 K [Fig. 7(b)]. This transfer takes place in a much smaller energy range compared to the SW transfer caused by the primary CDW gap. It indicates an additional gap that becomes visible around 50 K. An estimate of both gaps can be given using the second derivative, as shown in Fig. 7(c). In this representation, we can also estimate approximately the main scaling below T_{CDW} : The high-energy zero crossing marks the high-temperature energy scale of the gap, and an additional zero crossing below 50 K is related with the additional contribution. We suggest that this second energy scale is also related to the density-wave formation and serves as the bulk probe for the multigap scenario inferred from the ARPES measurements that reported the gaps of 130 and 80 meV, both of them highly anisotropic across the Brillouin zone [12]. Since this anisotropy is averaged out in the optical measurement, the exact gap values may differ from those in ARPES, but the qualitative behavior is remarkably similar.

Furthermore, the larger energy gap shows a rather abrupt increase right below T_{CDW} , where the behavior is in line with the other AV_3Sb_5 systems [27,28]. On the other hand, the smaller energy gap seems to develop gradually with a mean-field-like behavior. However, we should point out that the exact onset temperature for this second gap cannot be determined with the current measurements.

The CDW in RbV₃Sb₅ is rather unusual. The opening of a density-wave gap will usually lead to an abrupt increase in the dc resistivity caused by the reduction in the density of states [55]. In contrast, the mere kink observed in the dc resistivity of RbV₃Sb₅ at T_{CDW} suggests that the mobile carriers are not significantly affected by the CDW formation. It is then plausible that the localization peak is caused by the bands in the vicinity of the *M* point that become gapped below T_{CDW} [12,29], whereas the Drude peak is due to mobile carriers that reside on other bands crossing the Fermi level.

E. Phonon modes

Besides these electronic features, the room-temperature spectrum shows two modes reminiscent of phonon excitations at, respectively, 160 and 430 cm⁻¹ [Fig. 8(b)]. While the low-energy mode is readily assigned to the IR-active E_{1u} phonon according to our DFT calculations [Fig. 8(a)], the high-energy mode has the unusual Fano-like shape and cannot be interpreted in the same manner as the lower mode, because no IR-active phonons are found above 250 cm⁻¹ in DFT [Fig. 8(a)]. Experimentally, both modes show strong anomalies across T_{CDW} , as well as indications for a strong coupling to the electronic background.

The lower 160 cm⁻¹ mode can be represented with a single Lorentzian,

$$\sigma_1(\omega) = \frac{\Delta \epsilon \, \omega^2 \omega_0^2 \gamma}{4\pi \left[\left(\omega^2 - \omega_0^2 \right)^2 + \gamma^2 \omega^2 \right]}.$$
(5)

Here, ω_0 , $\Delta\epsilon$, and γ stand for the resonance frequency, intensity, and linewidth of the phonon mode, respectively. The obtained parameters in Figs. 8(c)–8(e) reveal a strong increase



FIG. 8. (a) Phonon frequencies calculated for the undistorted structure. The black line marks the E_{1u} mode observed in the experimental spectra. (b) Low-energy optical conductivity, highlighting the observed phonon mode and Fano antiresonance with the solid lines. The gray lines are fits to the optical spectra. The spectra are shifted for clarity. The fit parameters obtained from the curves in (b) are given in (c)–(e) for the phonon mode and (f)–(i) for the Fano antiresonance. The blue and green lines correspond to T_{CDW} and the onset temperature of the lower CDW gap, respectively.

in the intensity $\Delta \varepsilon$ along with a pronounced redshift upon approaching the CDW transition and also below T_{CDW} . This is contrary to the standard temperature evolution of the phonon modes that show the blueshift upon cooling as the lattice hardens. At low temperatures, the mode is masked by the localization peak that has a strong influence on the obtained parameters. The increased broadening upon cooling is a signature of the strong electron-phonon coupling. This coupling is probably important for the appearance of the mode in the optical spectrum, because phonons in metals are usually screened by conduction electrons. Such a screening may be responsible for the absence of three other E_{1u} modes, whereas three more modes (out of seven IR-active modes in total) have the A_{2u} symmetry and involve out-of-plane atomic displacements that do not couple to light in our in-plane measurement geometry.

The higher 430 cm^{-1} mode is better reproduced by a Fanolike response [56],

$$\sigma_{1}(\omega) = \frac{\sigma_{0}\omega\gamma \left[\gamma\omega(q^{2}-1)+2q(\omega^{2}-\omega_{0}^{2})\right]}{4\pi \left[\left(\omega^{2}-\omega_{0}^{2}\right)^{2}+\gamma^{2}\omega^{2}\right]}.$$
 (6)

The additional parameter q is the dimensionless coupling constant that describes the asymmetry of the mode and also gauges the scale of the coupling to the electronic background. We note that q also takes negative values, as the high-energy mode is a strong antiresonance. The obtained parameters for the antiresonance are given in Figs. 8(f)-8(i). A similar redshift of the resonance frequency ω_0 is accompanied by an increase in the intensity σ_0 . In contrast to the lowenergy mode, this feature sharpens upon cooling, which is the expected behavior with decreasing thermal effects. The coupling parameter, $q \approx -3$, remains similar across the whole temperature range and suggests that the coupling persists even below T_{CDW} . While the anomalies at T_{CDW} are clearly visible, a closer look at the variables reveals also the secondary anomalies around 50 K, such as the sudden increase in the intensity, suggesting that the antiresonance responds to changes in the electronic structure when the second CDW gap appears.

The fact that the high-energy mode cannot be assigned to a Γ -point phonon goes hand in hand with the unusual, antiresonance nature of this mode. A similar antiresonance has been observed in KV_3Sb_5 around 480 cm⁻¹, but in that case it could be regarded as an overtone of a Γ -point phonon [28]. Such an interpretation is clearly excluded in RbV₃Sb₅ where no IR-active phonon appears in the 200–220 cm⁻¹ range. On the other hand, such a mode could arise from a non- Γ phonon as a result of a strong interaction with the electronic degree of freedom. Similar antiresonances have been discussed in functionalized graphene and modeled with the involvement of the K-point phonons [57]. Considering the CDW formation combined with the unusual behavior of this antiresonance, phason modes could also be envisaged similar to materials with an incommensurate CDW [58–61]. However, these phason modes have been shown to appear along the out-of-plane direction and only at low energies. None of these conditions apply to our case, as the CDW order is commensurate, while the observed mode is an in-plane one and resides at a relatively high energy. Therefore, we deem the phason scenario unlikely. An interesting observation regarding the antiresonance is its prominent redshift that mirrors the redshift of the localization peak (Sec. IIIC), although the former appears only below $T_{\rm CDW}$, while the latter is observed over the entire temperature range.



FIG. 9. (a) Calculated band structure of RbV₃Sb₅. (b) Calculated σ_{xx} component of the optical conductivity and its band-resolved contributions. The Fermi level is shifted upwards by 41 meV.

F. Interband transitions

The interband transitions are elucidated by DFT calculations of the optical conductivity. As seen in Fig. 9(b), the low-energy contributions to the in-plane optical conductivity σ_{xx} are restricted to the transitions between bands *B* and *C*, which occur in the vicinity of the *L* and *M* points of the Brillouin zone [see Fig. 9(a)]. In the 0.2–1.0 eV range, the optical conductivity is dominated by three contributions that arise from the transitions $A \rightarrow C$, $B \rightarrow D$, and $B \rightarrow E$.

The experimental interband conductivity is given in Fig. 10(a) below and above T_{CDW} , after the Drude, localization, and phonon modes have been subtracted to allow for a direct comparison with the DFT results presented in Fig. 10(b). We find a good agreement between experiment and calculations in the normal state when the Fermi level is shifted upwards by 41 meV. A similar upward shift by 64 meV was required in the case of KV₃Sb₅ [28], indicating that both compounds deviate from the band picture, and a slight renormalization of band energies is required for a proper description of their electronic structure.

For the density-wave state, two different distorted structures were considered according to the star-of-David and trihexagonal in-plane distortions (demonstrated in Fig. 1), as discussed in Refs. [28,50,62,63]. The position of the additional peak in the spectrum below T_{CDW} is best reproduced by the star-of-David CDW. On the other hand, this model also predicts a broad low-energy absorption feature, which we do not see in the experiment. Moreover, the peak around 70 meV in the experimental spectrum is not seen in the calculated star-of-David spectrum, however, it is reproduced by the trihexagonal CDW. We also note that the trihexagonal CDW



FIG. 10. (a) Experimental interband transitions at 110 K (normal state) and 10 K (CDW state). (b) Calculated optical conductivity given for the normal state, as well as for the two possible types of distortions (star of David and trihexagonal). (c) Band dispersions for the CDW phases of RbV₃Sb₅ shown in the Brillouin zone of the 2×2 superstructure. Note that the *M'*, *K'*, *L'*, and *H'* points are different from the respective *M*, *K*, *L*, and *H* points for the normal state. The *M* of the normal state is mapped onto Γ for the 2×2 superstructure.

has a higher stabilization energy of 5 meV/f.u. (relative to the normal state) compared to 1.5 meV/f.u. for the star-of-David CDW.

In Fig. 10(c), we show calculated band dispersions for the two possible CDW states. Both types of CDW are metallic, in agreement with the persistent metallicity of RbV₃Sb₅ below T_{CDW} . On the other hand, a gap opening for some of the bands gives rise to multiple flat bands along Γ -A. The peak of the interband absorption is probably caused by optical transitions between such flat bands. Their larger separation in the trihexagonal case is consistent with the shift of this peak toward higher energies.

The direct comparison of the optical spectra of all three compounds of the AV_3Sb_5 series reveals important changes in the band structure and electron dynamics that appear prominently in the low-energy optical response. The interband transitions and the redshifting localization peak are common across the whole series. Moreover, the sharp Drude peak mirrors the highly metallic nature of these systems. On the other hand, several differences need to be pointed out.



FIG. 11. (a) Calculated interband optical conductivity for KV_3Sb_5 , CsV_3Sb_5 , and RbV_3Sb_5 in the normal state. (b) Comparison of the calculated band structures around the *M* point. The differences in the band saddle points are clearly visible. The Fermi level is shifted upwards by 41 and 64 meV for RbV_3Sb_5 and KV_3Sb_5 , respectively.

М

► K

Г

-

(i) The Drude scattering is strongest in RbV₃Sb₅, causing a very broad Drude peak and a nearly flat optical conductivity in the low-energy range at high temperatures, as it overlaps with the localization peak. (ii) The low-energy interband spectrum of RbV₃Sb₅ strongly resembles that of KV₃Sb₅ with one intense absorption peak below 1000 cm⁻¹, in contrast to the three weaker peaks in CsV₃Sb₅ [see Fig. 11(a)]. This change in the interband absorption reflects the differences in the band structure related to the positions of band saddle points around M, as shown in Fig. 11(b).

With the notation used in Ref. [15], the saddle points are identified as Γ_1^+ at -105 meV and Γ_3^+ at -70 meV in RbV₃Sb₅, -120 and -60 meV in KV₃Sb₅, and -30 and -95 meV in CsV₃Sb₅, respectively. The two saddle points are inverted in CsV₃Sb₅ with respect to the KV₃Sb₅ and RbV₃Sb₅. Experimentally, this inversion is clearly visible as the change in the interband absorption. From an electronic structure point of view, RbV₃Sb₅ appears to be more similar to KV₃Sb₅, yet its two saddle points become closer in energy, thus evolving toward the inverted case of CsV₃Sb₅.

Another interesting point is the deviation from the band picture across the AV_3Sb_5 series. It has been detected in KV_3Sb_5 and RbV_3Sb_5 , where an upward shift of the Fermi level was required in order to reproduce interband absorption with DFT. On the other hand, no such shift was needed in the case of CsV_3Sb_5 [27]. This difference can also be seen from the perspective of plasma frequencies that are compared between the experiment and DFT calculations. Previously, such a comparison of the experimental Drude spectral weight



FIG. 12. Ratio of the experimental and DFT-based spectral weights, $SW_{experiment}/SW_{band}$. The compounds of the AV_3Sb_5 series are shown with solid diamonds. Several topologically nontrivial Dirac/Weyl semimetals are shown for comparison (open circles) using the data from Ref. [64].

(plasma frequency squared) with the band theory was used as a gauge of electronic correlations in a series of materials, including cuprates, iron pnictides, and topologically nontrivial Dirac systems [64,65]. In this comparison, the scaling parameter SW_{experiment}/SW_{band} is close to 1 for uncorrelated materials such as simple metals and zero for the most correlated class of Mott insulators. Other classes of materials fall in between these two limits, with the ratios below 0.5 taken as indications for a highly correlated nature of the system.

In Fig. 12, we compare the scaling factors for the AV_3Sb_5 series. Experimental plasma frequencies for KV_3Sb_5 and CsV_3Sb_5 are taken from previous studies [27,28]. While KV_3Sb_5 is the most correlated member of the AV_3Sb_5 family, correlations seem to play only a minor role in CsV_3Sb_5 . This result corroborates our earlier observation that a renormalization of band energies should take place in KV_3Sb_5 but not in CsV_3Sb_5 . Finally, RbV_3Sb_5 takes an intermediate position, but lies notably closer to KV_3Sb_5 and deviates from the band picture too. The similarities in the phonon anomalies and Fano antiresonance are also common to KV_3Sb_5 and RbV_3Sb_5 . They may be associated with the moderately correlated nature of these compounds.

IV. CONCLUSIONS

A detailed temperature-dependent optical study is presented for RbV₃Sb₅ in the energy range of 10 meV–2 eV and at temperatures down to 10 K. Our data witness the highly metallic nature of the compound and the CDW transition at T_{CDW} . The evolution of the interband absorption across the AV_3Sb_5 series mirrors changes in the band structure and especially the rearrangement of the band saddle points (van Hove singularities) around M. The detailed comparison suggests a close similarity between RbV₃Sb₅ and KV₃Sb₅.

An unexpected feature of the low-energy optical response is the prominent localization peak that signals hindered electron dynamics. This localization peak coexists with the conventional Drude contribution and indicates the multiband nature of the compound as well as different carrier channels. In both RbV₃Sb₅ and CsV₃Sb₅, this peak shifts to low frequencies upon cooling and merges with the Drude peak at $T \rightarrow 0$. Therefore, the localization effects in these compounds should be mostly temperature driven and possibly related to phonons. On the other hand, the localization peak in KV₃Sb₅ remains at finite frequencies at $T \rightarrow 0$. This difference is in line with the enhanced correlation effects observed in KV₃Sb₅ (Fig. 12).

Below T_{CDW} , RbV₃Sb₅ shows clear signatures of two energy scales associated with the CDW. These energy scales are in a good agreement with ARPES and confirm the bulk nature of both energy gaps that could be previously detected by surface-sensitive techniques only. We note that the agreement between the experimental and calculated optical conductivities is clearly less favorable in the CDW state than in the normal state. Each of the CDW models—trihexagonal and star of David—reproduces certain features of the experimental data but fails to reproduce the entire spectrum. Together with the presence of two distinct energy gaps, this may indicate the combination of multiple order parameters and the need to combine different types of distortions for a realistic modeling of the CDW in RbV₃Sb₅ and in the whole AV_3 Sb₅ series.

Last but not least, the prominent modes at 160 and 430 cm⁻¹ both reveal a strong coupling to the electronic background and put forward electron-phonon coupling as an important ingredient of the AV_3Sb_5 physics. Intriguingly, the 430 cm⁻¹ mode with its strong antiresonance cannot be interpreted as an IR-active phonon or an overtone. Moreover, such Fano-like modes appear in KV_3Sb_5 and RbV_3Sb_5 that

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both show tangible deviations from the band picture, but not in CsV_3Sb_5 where the band picture holds. The intriguing electron-phonon coupling in the AV_3Sb_5 series certainly calls for a further dedicated investigation.

Note added. Recently, we became aware of muon spin relaxation (μ SR) measurements on RbV₃Sb₅ [66] that revealed a change in the CDW state below 50 K and suggested a different type of CDW order below this temperature. It is an independent bulk probe that corroborates our conclusion on the multiple CDW gaps in RbV₃Sb₅.

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